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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Mieher, et al.

Attorney Docket No.: KLA1P117X1B/P1151/3

Application No.: 10/785,395

Examiner: STOCK JR, GORDON J

Filed: February 23, 2004

Group: 2877

Title: APPARATUS AND METHODS FOR DETECTING OVERLAY ERRORS USING

SCATTEROMETRY

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first-class mail on May 13, 2005 in an envelope addressed to the Commissioner for Patents, P.O. Box 1450 Alexandria, VA 22313-1459.

Signed:

INFORMATION DISCLOSURE STATEMENT 37 CFR §§1.56 AND 1.97(b)

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

The references listed in the attached PTO Form 1449, copies of which are attached, may be material to examination of the above-identified patent application. Applicants submit these references in compliance with their duty of disclosure pursuant to 37 CFR §§1.56 and 1.97. The Examiner is requested to make these references of official record in this application.

This Information Disclosure Statement is not to be construed as a representation that a search has been made, that additional information material to the examination of this application does not exist, or that these references indeed constitute prior art.

This Information Disclosure Statement is: (i) filed within three (3) months of the filing date of the above-referenced application, (ii) believed to be filed before the mailing date of a first Office Action on the merits, or (iii) believed to be filed before the mailing of a first Office Action after the filing of a Request for Continued Examination under §1.114. Accordingly, it is believed that no fees are due in connection with the filing of this Information Disclosure Statement. However, if it is determined that any fees are due, the Commissioner is hereby authorized to charge such fees to Deposit Account 500388 (Order No. KLA1P117X1B).

Respectfully submitted,

REYER WEAVER & THOMAS, LLP

Mary Ramos Olynick Registration No. 42,963

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Form 1449 (Modified)

Information Disclosure Statement By Applicant

(Use Several Sheets if Necessary)

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Mieher, et al.

Filing Date February 23, 2004 Group 2877

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	A6	4,999,014	03/12/91	Go	ld et al.	356	382	05/04/89
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Form 1449 (Modified)

Information Disclosure Statement By Applicant

(Use Several Sheets if Necessary)

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Mieher, et al. Filing Date

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	B5	6,081,325	06/27/00	Les	lie et al.	356	237.2	06/03/97
	В6	4,818,110	04/04/89	Dav	vidson	356	358	05/06/86
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Form 1449 (Modified)	Atty Docket No.	Application No.:
	KLA1P117X1B/P1151/3	10/785,395
Information Disclosure	Applicant:	
Statement By Applicant	Mieher, et al.	
	Filing Date	Group
(Use Several Sheets if Necessary)	February 23, 2004	2877

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	C5	5,414,514	05/09/95	Sm	ith et al.	356	363	06/01/93
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	D5	WO/85/04266	26.09.85	WIPO	G03B	41/00	X	
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	D7	WO03042629	22.05.03	WIPO	G01B	11/00	X	
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	D9	WO/0218871	07.03.02	WIPO	G01B	11/27	X	
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	D11	WO/0215238	21.02.02	WIPO	H01L	21/00	X	
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